VS-VSKDS409/150

Vishay Semiconductors



AAP Gen 7 (TO-240AA) **Power Modules Schottky Rectifier, 200 A**



AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS				
I _{F(AV)} 200 A				
V _R	150 V			
Package	AAP Gen 7 (TO-240AA)			
Circuit configuration	Two diodes doubler circuit			

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- UL approved file E78996
- Low thermal resistance
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS409/150 Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES				
I _{F(AV)}	Rectangular waveform	200	A			
V _{RRM}		150	V			
I _{FSM}	t _p = 5 μs sine	20 000	А			
V _F	200 A _{pk} , T _J = 125 °C	0.85	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-VSKDS409/150	UNITS		
Maximum DC reverse voltage	V _R	150	V		
Maximum static peak reverse voltage	V _{RRM}	150	v		



VS-VSKDS409/150



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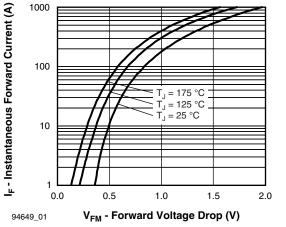
ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_C = 105 °C	, rectangular waveform	200	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	20 000	А
non-repetitive surge current	ion-repetitive surge current		rated V_{RRM} applied	2300	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH		15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А
Maximum dynamic peak reverse voltage	V _{AV}	$T_{J} = 25 \ ^{\circ}C, \ I_{AS} = 1.8 \ A, \ L = 10 \ r$	nH	170	V

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		200 A	T.I = 25 °C	1.03		
Maximum forward voltage drop	V	400 A	1j=25 0	1.33	v	
Maximum forward voltage drop	V _{FM}	200 A	T _{.1} = 125 °C	0.85	v	
		400 A	1j = 125 C	1.13		
	I _{RM}	T _J = 25 °C	V Deted V	6	mA	
Maximum reverse leakage current		T _J = 125 °C	V _R = Rated V _R	85		
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		6000	pF	
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		5.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	e	T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.32	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1		
Approvimeto weight				75	g	
Approximate weight				2.7	oz.	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the		Nm	
	busbar		spread of the compound.	3	INIT	
Case style		JEDEC [®] TO-24		TO-240AA co	ompatible	

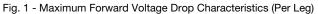
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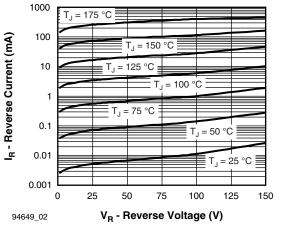
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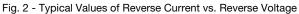


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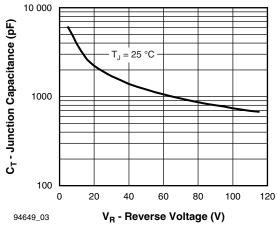


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

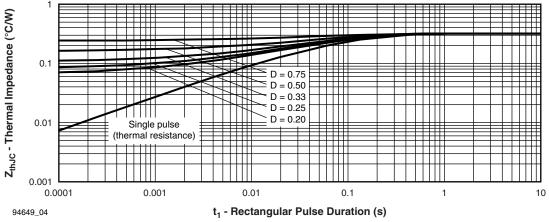
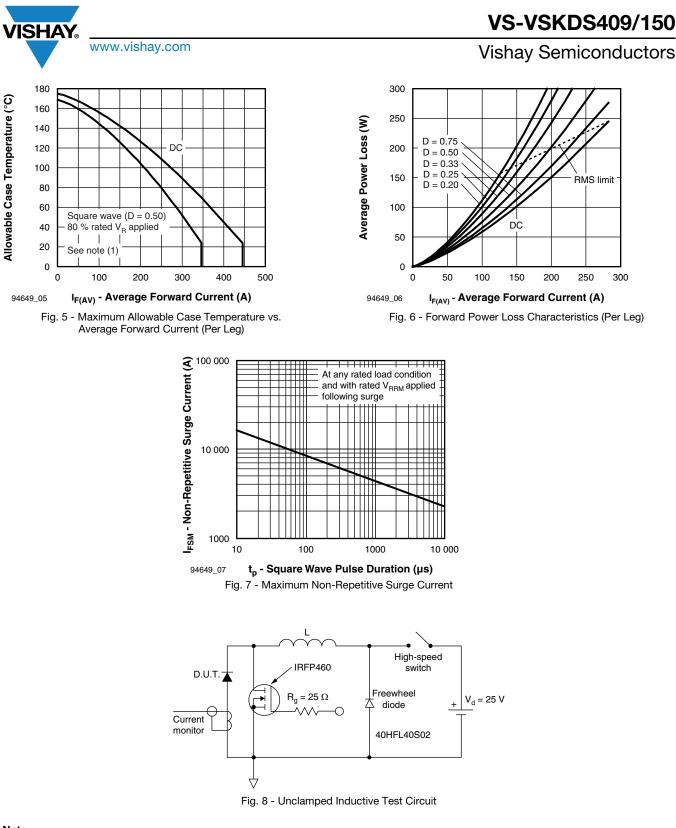


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

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Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
- Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 D)$; I_R at V_{R1} = 80 % rated V_R

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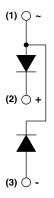
ORDERING INFORMATION TABLE

Device code	vs-vs	KD	S	40	9	1	150
		2	3	4	5		6
	 Vishay Semiconductors product Circuit configuration: 						
	KD = ADD-A-PAK - 2 diodes doubler circuit						
	3 - S = Schottky diode						
	4 -	Ave	erage cu	rrent rat	ing (40	= 400 A	() ⁽¹⁾
	5 -	Pro	duct sili	con iden	tificatio	n	
	6 -	Vol	tage rati	ng (150	= 150 \	/)	

Note

⁽¹⁾ For KD configuration average current rating per module is 200 A

CIRCUIT CONFIGURATION



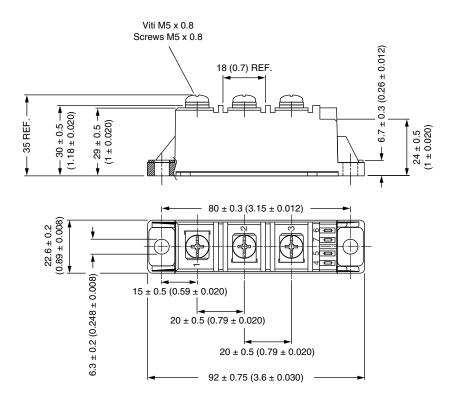
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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